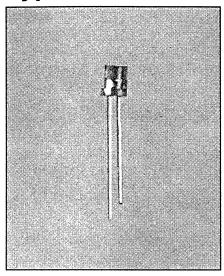
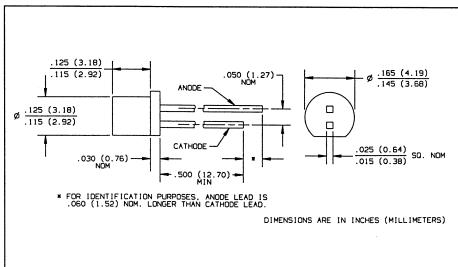


GaAs Plastic Infrared Emitting Diode Type OP165W





Features

- Wide irradiance pattern
- Mechanically and spectrally matched to the OP505W
- Small package size for space limited applications
- T-1 package style

Description

The OP165W is a 935nm high intensity gallium arsenide infrared emitting diode molded in an IR transmissive amber tinted epoxy package. The broad irradiance pattern provides relatively even illumination over a large area. This package is a T-1 style in all respects except for the length of the plastic package.

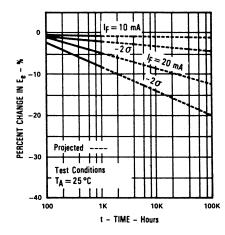
Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

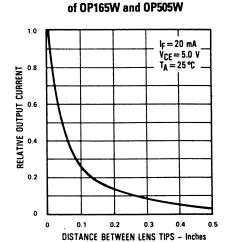
Reverse Voltage
Continuous Forward Current
Peak Forward Current (1 µs pulse width, 300 pps) 3.0 A
Storage and Operating Temperature Range
Lead Soldering Temperature [1/16 inch (1.6mm) from case for 5 sec. with soldering
iron]
Power Dissipation
Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 sec. max. when flow soldering. A max. of 20 grams force may be applied to the leads when soldering.
- (2) Derate linearly 1.33 mW/° C above 25° C.

Typical Performance Curves

Percent Changes in Power Output vs Time





Coupling Characteristics

Type OP165W

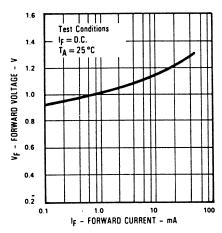
Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Po	Radiant Power Output	0.50			mW	I _F = 20 mA
V _F	Forward Voltage			1.60	V	I _F = 20 mA
IR	Reverse Current			100	μΑ	V _R = 2.0 V
λр	Wavelength at Peak Emission		935		nm	I _F = 10 mA
В	Spectral Bandwidth Between Half Power Points		50		nm	I _F = 10 mA
Δλρ/ΔΤ	Spectral Shift with Temperature		+0.30		nm/°C	I _F = Constant
θнр	Emission Angle at Half Power Points		90		Deg.	I _F = 20 mA
tr	Output Rise Time		1000		ns	I _{F(PK)} = 100 mA,
tf	Output Fall Time		500		ns	PW = 10 μs, D.C. = 10.0%

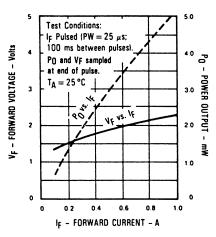


Typical Performance Curves

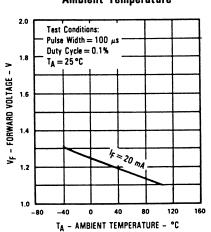




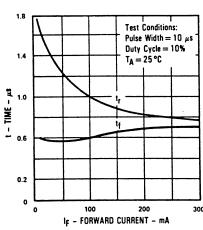
Forward Voltage and Power Output vs Forward Current



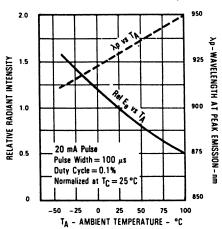
Forward Voltage vs **Ambient Temperature**



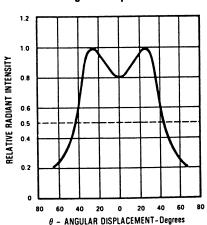
Rise Time and Fall Time vs **Forward Current**



Normalized Power Output and Wavelength at Peak Emission vs Ambient Temperature



Relative Radiant Intensity vs **Angular Displacement**



Optek reserves the right to make changes at any time in order to improve design and to supply the best product possible.